

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

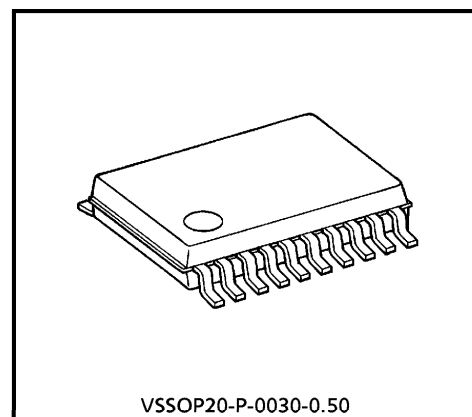
**TC7MA573FK****LOW-VOLTAGE OCTAL D-TYPE LATCH  
WITH 3.6 V TOLERANT INPUTS AND OUTPUTS**

The TC7MA573FK is a high performance CMOS OCTAL D-TYPE LATCH. Designed for use in 1.8, 2.5 or 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation. It is also designed with over voltage tolerant inputs and outputs up to 3.6V.

This 8 bit D-type latch is controlled by a latch enable input (LE) and an output enable input ( $\overline{OE}$ ).

When the  $\overline{OE}$  input is high, the eight outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge.



VSSOP20-P-0030-0.50

Weight : 0.03 g (typ.)

**Features**

- Low Voltage Operation :  $V_{CC} = 1.8\sim 3.6\text{ V}$
- High Speed Operation :  $t_{pd} = 4.2\text{ ns (max) at } V_{CC} = 3.0\sim 3.6\text{ V}$   
 $t_{pd} = 4.7\text{ ns (max) at } V_{CC} = 2.3\sim 2.7\text{ V}$   
 $t_{pd} = 9.4\text{ ns (max) at } V_{CC} = 1.8\text{ V}$
- 3.6 V Tolerant inputs and output.
- Output Current :  $I_{OH}/I_{OL} = \pm 24\text{ mA (min) at } V_{CC} = 3.0\text{ V}$   
 $I_{OH}/I_{OL} = \pm 18\text{ mA (min) at } V_{CC} = 2.3\text{ V}$   
 $I_{OH}/I_{OL} = \pm 6\text{ mA (min) at } V_{CC} = 1.8\text{ V}$
- Latch-up Performance :  $\pm 300\text{ mA}$
- ESD Performance : Human Body Model  $> \pm 2000\text{ V}$   
Machine Model  $> \pm 200\text{ V}$
- Package : VSSOP (US20)
- Power Down Protection is provided on all inputs and outputs.
- Supports live insertion / withdrawal (Note 1)

(Note 1): To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

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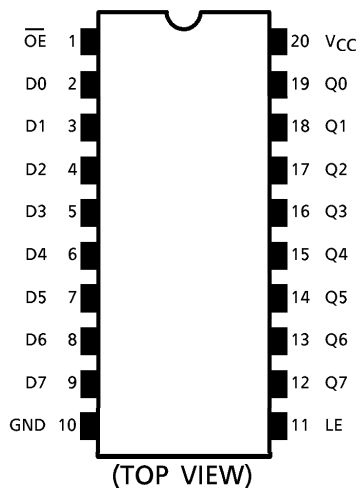
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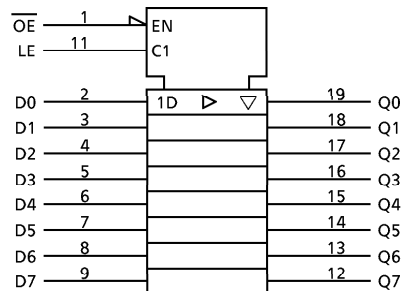
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**Pin Assignment**



**IEC Logic Symbol**

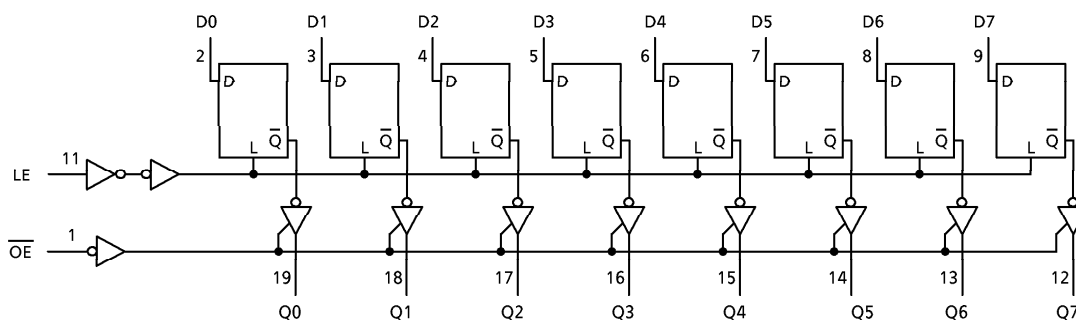


**Truth Table**

INPUTS			OUTPUTS
OE	LE	D	
H	X	X	Z
L	L	X	Qn
L	H	L	L
L	H	H	H

- X : Don't Care
- Z : High Impedance
- Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

**System Diagram**



## Maximum Ratings

PARAMETER	SYMBOL	RATING	UNIT
Power Supply Voltage	$V_{CC}$	-0.5~4.6	V
DC Input Voltage	$V_{IN}$	-0.5~4.6	V
DC Output Voltage	$V_{OUT}$	-0.5~4.6 (Note 1)	V
		-0.5~ $V_{CC}$ + 0.5 (Note 2)	
Input Diode Current	$I_{IK}$	-50	mA
Output Diode Current	$I_{OK}$	±50 (Note 3)	mA
DC Output Current	$I_{OUT}$	±50	mA
Power Dissipation	$P_D$	180	mW
DC $V_{CC}$ /Ground Current	$I_{CC}/I_{GND}$	±100	mA
Storage Temperature	$T_{stg}$	-65~150	°C

(Note 1): Off-State

(Note 2): High or Low State.  $I_{OUT}$  absolute maximum rating must be observed.

(Note 3):  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$

## Recommended Operating Range

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	$V_{CC}$	1.8~3.6	V
		1.2~3.6 (Note 4)	
Input Voltage	$V_{IN}$	-0.3~3.6	V
Output Voltage	$V_{OUT}$	0~3.6 (Note 5)	V
		0~ $V_{CC}$ (Note 6)	
Output Current	$I_{OH}/I_{OL}$	±24 (Note 7)	mA
		±18 (Note 8)	
		±6 (Note 9)	
Operating Temperature	$T_{opr}$	-40~85	°C
Input Rise And Fall Time	$dt/dv$	0~10 (Note 10)	ns/V

(Note 4): Data Retention Only

(Note 5): Off-State

(Note 6): High or Low State

(Note 7):  $V_{CC} = 3.0\sim 3.6$  V

(Note 8):  $V_{CC} = 2.3\sim 2.7$  V

(Note 9):  $V_{CC} = 1.8$  V

(Note 10):  $V_{IN} = 0.8\sim 2.0$  V,  $V_{CC} = 3.0$  V

**Electrical Characteristics**

DC characteristics (Ta = -40~85°C, 2.7 V < VCC ≤ 3.6 V)

PARAMETER		SYMBOL	TEST CONDITION	VCC (V)	Min	Max	UNIT	
Input Voltage	"H" Level	V <sub>IH</sub>		2.7~3.6	2.0	—	V	
	"L" Level	V <sub>IL</sub>		2.7~3.6	—	0.8		
Output Voltage	"H" Level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	2.7~3.6	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -12 mA	2.7	2.2	—	
				I <sub>OH</sub> = -18 mA	3.0	2.4	—	
				I <sub>OH</sub> = -24 mA	3.0	2.2	—	
	"L" Level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.7~3.6	—	0.2	
				I <sub>OL</sub> = 12 mA	2.7	—	0.4	
				I <sub>OL</sub> = 18 mA	3.0	—	0.4	
				I <sub>OL</sub> = 24 mA	3.0	—	0.55	
Input Leakage Current		I <sub>IN</sub>	V <sub>IN</sub> = 0~3.6 V	2.7~3.6	—	± 5.0	μA	
3-State Output Off-State Current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0~3.6 V	2.7~3.6	—	± 10.0	μA	
Power Off Leakage Current		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0~3.6 V	0	—	10.0	μA	
Quiescent Supply Current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	2.7~3.6	—	20.0	μA	
			V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V	2.7~3.6	—	± 20.0		
Increase In I <sub>CC</sub> Per Input		ΔI <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V	2.7~3.6	—	750	μA	

**Electrical Characteristics**

DC characteristics (Ta = -40~85°C, 2.3 V ≤ VCC ≤ 2.7 V)

PARAMETER		SYMBOL	TEST CONDITION	VCC (V)	Min	Max	UNIT	
Input Voltage	"H" Level	V <sub>IH</sub>		2.3~2.7	1.6	—	V	
	"L" Level	V <sub>IL</sub>		2.3~2.7	—	0.7		
Output Voltage	"H" Level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	2.3~2.7	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -6 mA	2.3	2.0	—	
				I <sub>OH</sub> = -12 mA	2.3	1.8	—	
				I <sub>OH</sub> = -18 mA	2.3	1.7	—	
	"L" Level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.3~2.7	—	0.2	
				I <sub>OL</sub> = 12 mA	2.3	—	0.4	
				I <sub>OL</sub> = 18 mA	2.3	—	0.6	
Input Leakage Current		I <sub>IN</sub>	V <sub>IN</sub> = 0~3.6 V	2.3~2.7	—	± 5.0	μA	
3-State Output Off-State Current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0~3.6 V	2.3~2.7	—	± 10.0	μA	
Power Off Leakage Current		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0~3.6 V	0	—	10.0	μA	
Quiescent Supply Current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	2.3~2.7	—	20.0	μA	
			V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V	2.3~2.7	—	± 20.0		

## Electrical Characteristics

DC characteristics ( $T_a = -40\sim 85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{CC} < 2.3\text{ V}$ )

PARAMETER		SYMBOL	TEST CONDITION		$V_{CC}$ (V)	Min	Max	UNIT
Input Voltage	"H" Level	$V_{IH}$			1.8~2.3	$0.7 \times V_{CC}$	—	V
	"L" Level	$V_{IL}$			1.8~2.3	—	$0.2 \times V_{CC}$	
Output Voltage	"H" Level	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -100\ \mu\text{A}$	1.8	$V_{CC} - 0.2$	—	V
				$I_{OH} = -6\ \text{mA}$	1.8	1.4	—	
	"L" Level	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 100\ \mu\text{A}$	1.8	—	0.2	
				$I_{OL} = 6\ \text{mA}$	1.8	—	0.3	
Input Leakage Current		$I_{IN}$	$V_{IN} = 0\sim 3.6\ \text{V}$		1.8	—	$\pm 5.0$	$\mu\text{A}$
3-State Output Off-State Current		$I_{OZ}$	$V_{IN} = V_{IH}$ or $V_{IL}$ $V_{OUT} = 0\sim 3.6\ \text{V}$		1.8	—	$\pm 10.0$	$\mu\text{A}$
Power Off Leakage Current		$I_{OFF}$	$V_{IN}, V_{OUT} = 0\sim 3.6\ \text{V}$		0	—	10.0	$\mu\text{A}$
Quiescent Supply Current		$I_{CC}$	$V_{IN} = V_{CC}$ or GND		1.8	—	20.0	$\mu\text{A}$
			$V_{CC} \leq (V_{IN}, V_{OUT}) \leq 3.6\ \text{V}$		1.8	—	$\pm 20.0$	

AC characteristics (Ta = -40~85°C, Input tr = tf = 2.0 ns, CL = 30 pF, RL = 500 Ω)

PARAMETER	SYMBOL	TEST CONDITION	VCC (V)	Min	Max	UNIT
Propagation Delay Time (D-Q)	t <sub>pLH</sub> t <sub>pHL</sub>	(Fig.1, 2)	1.8	1.5	9.4	ns
			2.5 ± 0.2	0.8	4.7	
			3.3 ± 0.3	0.6	4.2	
Propagation Delay Time (LE-Q)	t <sub>pLH</sub> t <sub>pHL</sub>	(Fig.1, 2)	1.8	1.5	9.8	ns
			2.5 ± 0.2	0.8	4.9	
			3.3 ± 0.3	0.6	4.2	
3-State Output Enable Time	t <sub>pZL</sub> t <sub>pZH</sub>	(Fig.1, 3)	1.8	1.5	9.8	ns
			2.5 ± 0.2	0.8	5.5	
			3.3 ± 0.3	0.6	4.5	
3-State Output Disable Time	t <sub>pLZ</sub> t <sub>pHZ</sub>	(Fig.1, 3)	1.8	1.5	6.5	ns
			2.5 ± 0.2	0.8	3.6	
			3.3 ± 0.3	0.6	3.3	
Minimum Pulse Width	t <sub>w</sub> (H)	(Fig.1, 2)	1.8	4.0	—	ns
			2.5 ± 0.2	1.5	—	
			3.3 ± 0.3	1.5	—	
Minimum Set-up Time	t <sub>s</sub>	(Fig.1, 2)	1.8	2.5	—	ns
			2.5 ± 0.2	1.5	—	
			3.3 ± 0.3	1.5	—	
Minimum Hold Time	t <sub>h</sub>	(Fig.1, 2)	1.8	1.0	—	ns
			2.5 ± 0.2	1.0	—	
			3.3 ± 0.3	1.0	—	
Output To Output Skew	t <sub>osLH</sub> t <sub>osHL</sub>	(Note 11)	1.8	—	0.5	ns
			2.5 ± 0.2	—	0.5	
			3.3 ± 0.3	—	0.5	

For CL = 50 pF, add approximately 300 ps to the AC maximum specification.

(Note 11): Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

Dynamic switching characteristics (Ta = 25°C, Input tr = tf = 2.5 ns, CL = 30 pF)

PARAMETER	SYMBOL	TEST CONDITION	VCC (V)	Typ.	UNIT
Quiet Output Maximum Dynamic VOL	VOLP	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V (Note 12)	1.8	0.25	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V (Note 12)	2.5	0.6	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Note 12)	3.3	0.8	
Quiet Output Minimum Dynamic VOL	VOLV	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V (Note 12)	1.8	-0.25	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V (Note 12)	2.5	-0.6	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Note 12)	3.3	-0.8	
Quiet Output Minimum Dynamic VOH	VOHV	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V (Note 12)	1.8	1.5	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V (Note 12)	2.5	1.9	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Note 12)	3.3	2.2	

(Note 12): Parameter guaranteed by design.

Capacitive characteristics (Ta = 25°C)

PARAMETER	SYMBOL	TEST CONDITION	VCC (V)	Typ.	UNIT
Input Capacitance	C <sub>IN</sub>		1.8, 2.5, 3.3	6	pF
Output Capacitance	C <sub>OUT</sub>		1.8, 2.5, 3.3	7	pF
Power Dissipation Capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz (Note 13)	1.8, 2.5, 3.3	20	pF

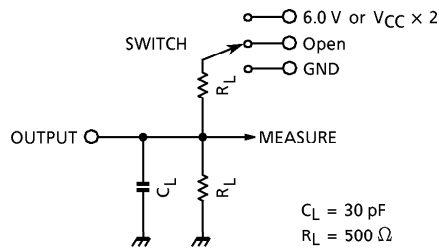
(Note 13): C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 8 \text{ (per bit)}$$

**Test Circuit**

Fig.1



PARAMETER	SWITCH
$t_{pLH}, t_{pHL}$	Open
$t_{pLZ}, t_{pZL}$	6.0 V @ $V_{CC} = 3.3 \pm 0.3$ V $V_{CC} \times 2$ @ $V_{CC} = 2.5 \pm 0.2$ V @ $V_{CC} = 1.8$ V
$t_{pHZ}, t_{pZH}$	GND

**AC Waveform**

Fig.2  $t_{pLH}, t_{pHL}, t_w, t_s, t_h$

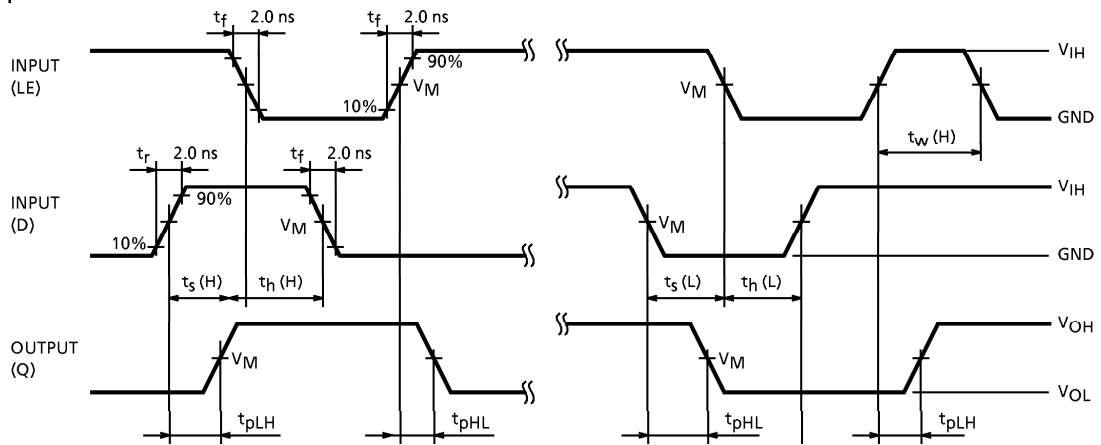
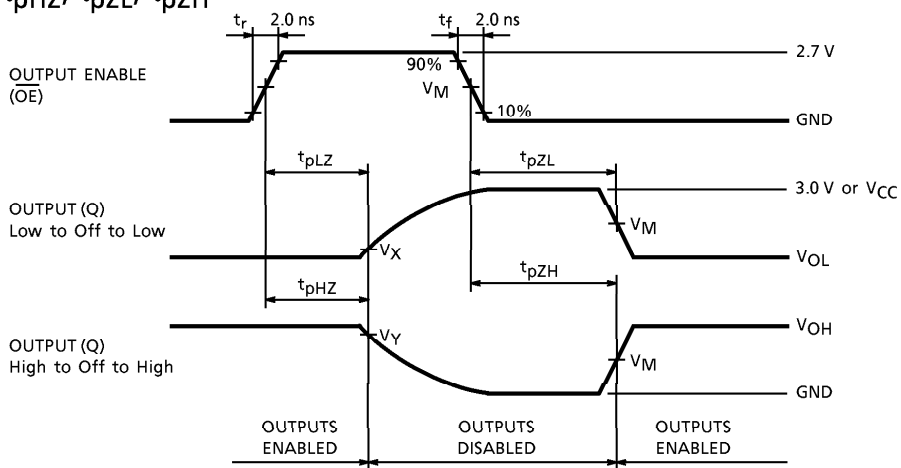


Fig.3  $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$

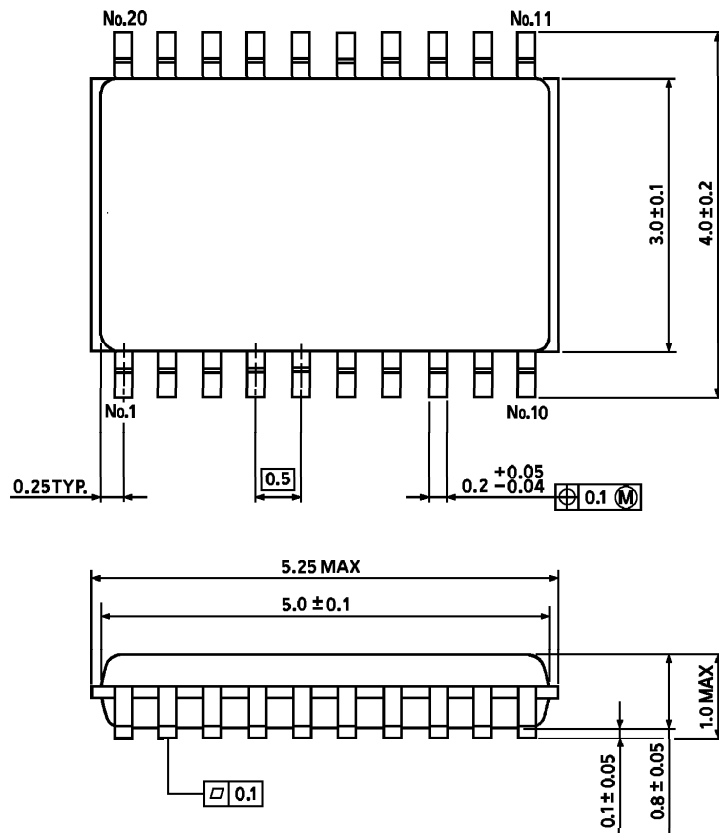


SYMBOL	$V_{CC}$		
	$3.3 \pm 0.3$ V	$2.5 \pm 0.2$ V	1.8 V
$V_{IH}$	2.7 V	$V_{CC}$	$V_{CC}$
$V_M$	1.5 V	$V_{CC} / 2$	$V_{CC} / 2$
$V_X$	$V_{OL} + 0.3$ V	$V_{OL} + 0.15$ V	$V_{OL} + 0.15$ V
$V_Y$	$V_{OH} - 0.3$ V	$V_{OH} - 0.15$ V	$V_{OH} - 0.15$ V



**Outline Drawing**  
VSSOP20-P-0030-0.50

Unit : mm



Weight : 0.03 g (typ.)